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I here the Legisland this correspondence is being deposited with the U.S. Postal Service with sufficient postage as first class mail in an envelope addressed to: Assistant Commissioner for Patents, Washington, D.C. 20231, on October 11, 2001.

Signature: Rule of A. Bouman

RECEIVED MAIL ROOM PATENT Attorney Docket No. NTI-019-2

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application)	PATENT APPLICATION
Inventor(s): Christophe Pierrat et al.)	A-4 TT-:4: 0010
Application No.: 09/675,197)	Art Unit: 2812
Filed: 09/29/2000)	Examiner: unknown
Title "Dissection Of Edges With Projection Points In A Fabrication Layout For Correcting Proximity Effects)))	

INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. §1.97

Assistant Commissioner for Patents Washington, D.C. 20231

Sir:

Listed below or one an attached Form PTO-1449 is information known to applicant(s). A copy of each listed publication and U.S. and foreign patent, except for pending U.S. applications, is being submitted herewith, along with a concise explanation of information in a foreign language, if any, pursuant to 37 C.F.R. §1.97-1.98.

Applicants respectfully request that the listed information be considered by the Examiner and be made of record in the above-identified application. If form PTO-1449 is enclosed, the Examiner is requested to initial and return it in accordance with MPEP § 609.

This statement is not intended to represent that a search has been made or that the information cited in the statement is, or is considered to be, material to patentability as defined in 37 C.F.R. § 1.56.

\boxtimes	This statement qualifies under 37 C.F.R. § 1.97, subsection (b) because (check all that apply):						
		(1)		as of the application filing date and is other than a application under § 1.53(d)			
		(2)	ns of entry of a national stage				
	\boxtimes	(3)	OR It is being filed before the mail OR	date of the first Office Action on the merits.			
		(4)		ling of a first Office Action after the filing of a request for under § 1.114			
	37 C.F.R. § 1.97(c). If this statement is being filed after the period specified in § 1.97(b), but before the mailing date of the earlier of a final office action under § 1.113, a notice of allowance under § 1.311, or an action that otherwise closes prosecution in the application, then:						
		a certif	fication as specified in § 1.97(e)	is provided below; or			
			f \$180.00 as set forth in § 1.17(pnt of other papers filed together	o) is authorized below, enclosed, or included with the with this statement.			
		-	R. § $1.97(d)$. If this statement is being filed after the period specified in § $1.97(c)$, but on or before of the issue fee, then:				
	A.	a certification as specified in § 1.97(e) is completed below; and					
	B.		f \$180.00 as set forth in § 1.17(pnt of other papers filed together	b) is authorized below, enclosed, or included with the with this statement.			
	and ch	arge any		y authorized to charge the above-referenced fees of \$ 180 erpayment associated with this communication to Deposit .			
				Respectfully submitted,			
				BEVER, HOFFMAN & HARMS, LLP			
Dated:	10	- [[- 01	By:			
Dateu.				Jeanette S. Harms, Reg. No. 35,537			
	one: (40 ier No.)8) 451-: 29477	5907				

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INEORMATION DISCLOSURE CITATION

ON 15 2011 PTO-1449

ATTY. DOCKET NO.

SERIAL NO.

NTI-019-2

09/675,197

APPLICANT Pierrat, et al.

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TA TRADEMA		U.S	. PATENT DOCUMENTS			
EXAMINER'S INITIALS	PATENT NO.	DATE	NAME	CLASS	SUBCLASS	FILING DATE
	4,231,811	11/4/80	Somekh, et al.	148	1.5	9/13/79
	4,456,371	6/26/84	Lin	355	71	6/30/82
	4,902,899	2/20/90	Lin, et al.	250	492.1	6/1/87
	5,498,579	3/12/96	Borodovsky, et al.	437	250	6/8/94
	5,553,274	9/3/96	Liebmann	395	500	6/6/95
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EXAMINER			DATE CONSIDERED			

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP § 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.



INFORMATION DISCLOSURE			ATTY. DOCKET NO.		SEF	RIAL NO.		
			NTI-019-2 09/675,197			575,197		
or 15 2001 Pr O-1449			APPLICANT Pierrat, et al.					
			FILING DATE 9/29/00 GROUP 2812					
PETE IRADEMA	*	FOR	EIGN PATENT DOCUMENTS					
EXAMINER'S	EXAMINER'S PATENT NO. DATE		COUNTRY	CLA	ASS	SUBCLASS	TRANS	LATION
INITIALS						n =	YES	NO
	3-210560	9/13/91	JP					
	8-236317	9/6/96	JP					
	10-133356	5/22/98	JP					
:	11-143085	5/28/99	JP					
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EVAMINED			DATE CONSIDERED					

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INFORMATION DISCLOSURE		ATTY. DOCKET NO.	SERIAL NO.			
4	CITATION	NT1-019-2	09/675,197			
OIPER	RTO-1449	APPLICANT Pierrat, et al.				
OCT 15 2001	* W. S.	FILING DATE 9/29/00	GROUP 2812			
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O P E P210-1449	APPLICANT Pierrat, et al.					
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